Technical Data Data Sheet 474, Rev.-

# SILICON SCHOTTKY RECTIFIER DIE Very Low Forward Voltage Drop

## **Applications:**

• Switching Power Supply • Converters • Free-Wheeling Diodes • Polarity Protection Diode

#### Features:

- Soft Reverse Recovery at Low and High Temperature
- Very Low Forward Voltage Drop
- Low Reverse Leakage Current
- Low Power Loss, High Efficiency
- High Surge Capacity
- Guard Ring for Enhanced Durability and Long Term Reliability
- Guaranteed Reverse Avalanche Characteristics
- Electrically / Mechanically Stable during and after Packaging

## Maximum Ratings<sup>(1)</sup>:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V <sub>RWM</sub>	-	200	V
Max. Average Forward Current	I <sub>F(AV)</sub>	50% duty cycle, rectangular wave form	7.5	A
Max. Peak One Cycle Non- Repetitive Surge Current	I <sub>FSM</sub>	8.3 ms, half Sine pulse	140	A
Non-Repetitive Avalanche Energy	$E_{AS}$	$T_J = 25 \text{ °C}, I_{AS} = 0.5 \text{ A},$ L = 60 mH	7.5	MJ
Repetitive Avalanche Current	I <sub>AR</sub>	$I_{AS}$ decay linearly to 0 in 1 µs f limited by T <sub>J</sub> max V <sub>A</sub> =1.5V <sub>R</sub>	0.5	A
Max. Junction Temperature	TJ	-	-65 to +200	°C
Max. Storage Temperature	$T_{stg}$	-	-65 to +200	°C

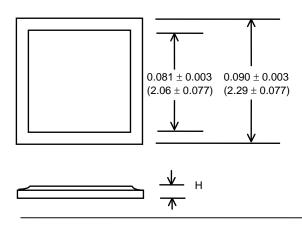
# **Electrical Characteristics**<sup>(1)</sup>:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V <sub>F1</sub>	@ 7.5A, Pulse, T <sub>J</sub> = 25 °C	0.92	V
	V <sub>F2</sub>	@ 7.5A, Pulse, T <sub>J</sub> = 125 °C	0.76	V
Max. Reverse Current	I <sub>R1</sub>	@V <sub>R</sub> = 200V, Pulse,	180	μA
		T <sub>J</sub> = 25 °C		
	I <sub>R2</sub>	@V <sub>R</sub> = 200V, Pulse,	4	MA
		T <sub>J</sub> = 125 °C		
Max. Junction Capacitance	CT	@V <sub>R</sub> = 5V, T <sub>C</sub> = 25 °C	150	PF
		f <sub>SIG</sub> = 1MHz,		
		$V_{SIG} = 50 \text{mV} (\text{p-p})$		

(1) in SHD package

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#### Mechanical Dimensions: In Inches / mm

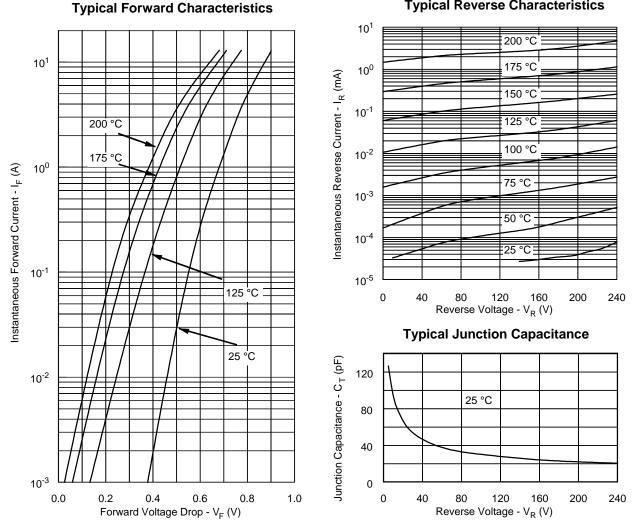


Bottom side metalization Ag - 30 kÅ minimum.

Top side metalization AI - 25 kÅ minimum or Ag - 30 kÅ minimum.

Bottom side is cathode, top side is anode.

Dimension H = 0.0105  $\pm$  0.001 (0.27  $\pm$  0.026) for AI top; Dimension H = 0.0155  $\pm$  0.001 (0.39  $\pm$  0.026) for Ag top.



**Typical Reverse Characteristics** 

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